









Solid State Photoelectrochemical Devices for Artificial Photosynthesis

Roel van de Krol Institute for Solar Fuels Helmholtz-Zentrum Berlin für Materialien und Energie GmbH and Institut für Chemie, Technische Universität Berlin, Germany

Three "Hard" Facts on Energy

- **Sunlight** is by far the most abundant and sustainable source of energy
- We need to **store** this energy on a GWh scale
- For long-term storage, **chemical fuels** are hard to beat



Importance of hydrogen:

- All fuels contain hydrogen
- Hydrogen is also needed for production of **food**, plastics, steel, etc.

Only <u>one</u> sustainable source: water!





Adapted from: Choudhury et al., *Green Chem.* 16, 4389 (2014)

Electrochemical Water Splitting



Clean Hydrogen Production



PV-Driven Electrolysis

- Many components \Rightarrow high costs
- Can be optimized individually
- Alkaline electrolysers corrode in the dark, PEM electrolyzers require noble metals
- Hydrogen can be produced at pressure



- Integrated device might be cheaper
- Heat easily used to accelerate reactions
- ✓ Current densities ~100x lower than in electrolyzers \Rightarrow earth-abundant catalysts
- Collection over large areas is challenging

Winning technology will be determined by Levelized Cost Of Hydrogen (€/kg H₂)

Photoelectrochemical Water Splitting at Semiconductor Surfaces



Unassisted PEC Water Splitting with SC / Liquid Junctions



Turner, Science (1998)

14%



May et al., Nat. Commun. (2015)





HZB/POSTECH/UNIST, Nat. Commun. (2016)

The Need for New Light Absorbers

- Missing component for multijunction absorber: stable and efficient top absorber with a 1.5 – 2.1 eV bandgap
- Combination with silicon offers path to solar-to-hydrogen (STH) efficiencies of ~20%
- Requirements: band gap, -positions, stability, carrier transport
- Our approach: focus on metal oxide absorbers

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Nat. Rev. Mater. 1, 15010 (2016)

CoPi-BiVO₄ / a-Si / a-Si Tandem Water Splitting Device



Towards Efficient BiVO₄ Photoanodes: Bottlenecks to Solve



[1] J. Phys. Chem. C 116 (2012) 9398; [2] ChemCatChem 5 (2013) 490; [3] Nat. Commun. 4:2195 (2013)

What Happens at the Surface of BiVO₄?

Performance limitations due to:

- Slow water oxidation kinetics
 - \rightarrow Solved by depositing CoPi OEC

Problem:

Modification of surface with traditional electrocatalysts does not always enhance the photocurrent:







Understanding Semiconductor / Catalyst Interfaces



Fatwa Carolin Abdi Zachäus



Possible functions of a "co-catalyst":

- Improve water oxidation kinetics
- Passivate surface defects
- Modify band bending
- Charge transfer rate hardly affected by CoPi: unexpected for electrocatalyst!
- Instead, CoPi strongly reduces recombination at BiVO₄ surface

Zachäus et al., Chem. Sci. 8, 3712 (2017)



Tentative Description of BiVO₄ / CoPi / Electrolyte Interface



- Surface states affect both charge transfer and recombination in BiVO₄
- ... what's the chemical nature of these states in BiVO₄?

Zachäus et al., *Chem. Sci.* 8, 3712 (2017)

AP-HAXPES Experiments at ALS Beamline 9.3.1



3λ1

 $3\lambda_2$



Zhi Liu, Ethan Crumlin (ALS)

Axnanda et al. Sci. Rep. 5, 09788 (2015)

Electrolyte layer

- Sample: spray-deposited BiVO₄ on FTO
- Photon energy of 4000 eV ⇒ mean free path of photoexcited electrons through water is ~30 nm
- 0.1 M KPi solution (Debye screening length $\lambda_D \sim 1$ nm)

AP-HAXPES Experiments at ALS Beamline 9.3.1



- From $H_2O(I)/BiVO_4$ ratio, electrolyte layer thickness ~21 nm \Rightarrow bulk properties
- Illumination increases the H_xPO₄ signal and gives Bi 4f shoulder consistent with BiPO₄

J. Electron Spectrosc. Relat. Phenom. 221, 106 (2017)

Tentative Model for BiVO₄ / Electrolyte Interface under Illumination





Upon illumination:

- 1. Protons leave the surface and are buffered by $KPi \Rightarrow increase in H_2PO_4^{-7}/HPO_4^{2-}$ ratio (IR)
- 2. Phosphate groups adsorbs at surface \Rightarrow negative charging explains $\triangle OCP$ of -30 mV
- 3. Other phosphate groups are repelled from BiVO₄/electrolyte to electrolyte/vapor interface \Rightarrow explains increase in H_xPO₄ signal

First tentative understanding of changes at BiVO₄/electrolyte interface under illumination

Resonant-XPS Spectra for 1% Mo:BiVO₄ (010)



Two electronic states identified in BiVO₄:

- Mo-induced deep V⁴⁺ bulk state at 0.91 eV above VBM
- Water-induced V⁴⁺-OH surface state at 0.50 eV above VBM

Time-Resolved Microwave Conductivity (TRMC)



State-of-the-art TRMC setup

- Uses cavity cell based on design of Savenije et al., TU Delft
- Enables direct measurement of carrier lifetime (τ) and mobility
 (μ) with >10x higher sensitivity
 - BiVO₄: $\mu = 0.044$ cm²/Vs, $\tau = 40$ ns



Abdi et al., J. Phys. Chem. Lett. 4, 2752 (2013)

Time-Resolved Spectroscopy on Absorber Materials



0

0

200

400

 τ [ps]

600

800

1000

But: quantum efficiency >80%...

⇒ Decay reflects decrease in carrier <u>mobility</u>, not in carrier concentration!



Dennis Friedrich



Rainer Eichberger

Evolution of photoexcited carriers in BiVO₄

- Free carriers \rightarrow trapping & polaron formation
- Carriers slow down enormously, but are still able to reach the interface
- Carrier dynamics very different than in 'normal' semiconductors

The Need for Chemically-Stable Wide-Bandgap Absorbers





- Mismatch in photocurrent from BiVO₄ and silicon
- New semiconductors needed that
 - have a smaller bandgap: 1.8 eV would enable 20% efficiency
 - are chemically **stable**, **efficient**, and **cheap**



- Bandgap ~1.7 eV
- Improved spray recipe gives smooth, dense films
- Surprisingly positive photocurrent onset potential
- Challenges: charge separation and stability

Berglund et al., Chem. Mater. 28, 4231 (2016); Wang et al., J. Mater. Chem. A 5, 12838 (2017)

How to Improve the Charge Separation in CuBi₂O₄?



- Copper vacancies (V_{Cu}") are the dominant defect in CuBi₂O₄
- By changing the concentration of V_{Cu}", the Fermi level changes
- A gradient in the V_{Cu}" concentration would then result in an electric field
- How to make a gradient in Cu vacancies?

Synthesis of CuBi₂O₄ with Gradient of Cu Vacancies



Sequential deposition of Bi₂O₃ and CuO layers by spray deposition

Wang et al., J. Am. Chem. Soc. 139, 15094 (2017)

Photoelectrochemical Characterization of CuBi₂O₄



- Forward-gradient films consistently show higher photocurrent densities
- CdS / TiO₂ / Pt deposited by David Tilley's group at Uni Zürich [1]
- Dramatic improvement in lifetime (but still not good enough)
- H₂ evolution photocurrent: -1.0 mA/cm² at 0 V_{RHE}, Faradaic efficiency ~91%

[1] Septina et al., *Chem. Mater.* 29, 1735 (2017)
[2] Wang et al., *J. Am. Chem. Soc.* 139, 15094 (2017)

Stand-alone 50 cm² Solar Fuel Device



Cell provided by group of

Adélio Mendes, Univ. Porto

Dual photoanode concept ^(*) to minimize charge transport losses in BiVO₄

^(*) Kim et al. *Nat. Commun.* 7, 13380 (2016)





Stand-alone 0.24 cm² Solar Fuel Device



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- BiVO₄ (2.4 eV) is a useful platform to learn about bulk and interfacial properties of oxides and scale-up challenges in PEC water splitting:
 - Surface recombination can dominate overall behavior
 - New operando X-ray methods give important new insights
 - Low mobility polaronic materials can still be efficient
- p-CuBi₂O₄ (1.7 eV) is a promising photocathode material
 - Gradient of intrinsic defects (Cu vacancies) helps charge separation
 - Stability needs to be improved
- Scale-up is hard, we need (electro)chemical engineers!

Progress in Oxide-Based Water Splitting Devices





HZB:

Fatwa Abdi, Jiwook Jang, Carolin Zachäus, David Starr, Marco Favaro, Sean Berglund, Rainer Eichberger, Sönke Müller, Dennis Friedrich, Manuel Ziwritsch, Karim Chemseddine, Yimeng Ma, Ibbi Ahmet, Fuxian Wang

Funding:

- BMBF Project "MeO_x4H₂"
- BMBF Project "GEP Grundlagen Elektrochemische Phasengrenzen"
- EU FCH-JU Project "PECDEMO" (#621252)

Collaborators:

- Matt Mayer, Michael Grätzel (EPFL)
- Bernd Stannowski, Simon Kirner (PVcomB)
- Adélio Mendes (University of Porto)
- Michael Wullenkord (DLR)
- Avner Rothschild (Technion)
- Solaronix SA, Evonik AG
- Laurie Peter (Univ. of Bath, UK)
- Hendrik Bluhm, Ethan Crumlin, beamlines
 9.3.1 and 11.0.2 (ALS, Berkeley)
- David Tilley (Univ. of Zürich)



Bundesministerium für Bildung und Forschung

HNSEI Helmholtz-NREL Solar Energy Initiative



